

1-of-8 Decoder/Demultiplexer MC74AC138, MC74ACT138

The MC74AC138/74ACT138 is a high-speed 1-of-8 decoder/demultiplexer. This device is ideally suited for high-speed bipolar memory chip select address decoding.

The multiple input enables allow parallel expansion to a 1–of–24 decoder using just three MC74AC138/74ACT138 devices or a 1–of–32 decoder using four MC74AC138/74ACT138 devices and one inverter.

- Demultiplexing Capability
- Multiple Input Enable for Easy Expansion
- Active LOW Mutually Exclusive Outputs
- Outputs Source/Sink 24 mA
- 'ACT138 Has TTL Compatible Inputs
- These are Pb-Free Devices

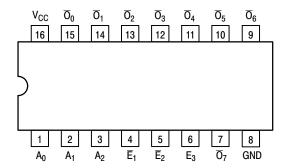


Figure 1. Pinout: 16-Lead Packages Conductors (Top View)

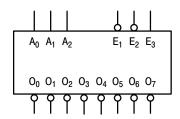


Figure 2. Logic Symbol

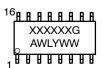
PIN ASSIGNMENT

PIN	FUNCTION					
A ₀ -A ₂	Address Inputs					
$\overline{E}_1 - \overline{E}_2$	Enable Inputs					
E ₃	Enable Input					
$\overline{O}_0 - \overline{O}_7$	Outputs					

MARKING DIAGRAMS



SOIC-16 D SUFFIX CASE 751B





TSSOP-16 DT SUFFIX CASE 948F



XXX = Specific Device Code A = Assembly Location

WL, L = Wafer Lot Y = Year WW, W = Work Week G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

FUNCTIONAL DESCRIPTION

The MC74AC138/74ACT138 high-speed 1-of-8 decoder/demultiplexer accepts three binary weighted inputs (A₀, A₁, A₂) and, when enabled, provides eight mutually exclusive active-LOW outputs (\overline{O}_0 - \overline{O}_7). The MC74AC138/74ACT138 features three Enable inputs, two active-LOW (\overline{E}_1 , \overline{E}_2) and one active-HIGH (E₃). All outputs will be HIGH unless \overline{E}_1 and \overline{E}_2 are LOW and E₃ is

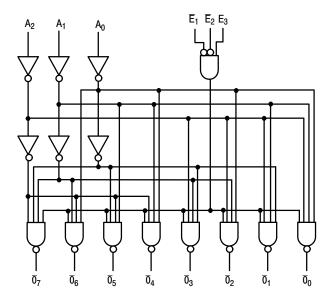
HIGH. This multiple enabled function allows easy parallel expansion of the device to a 1-of-32 (5 lines to 32 lines) decoder with just four MC74AC138/74ACT138 devices and one inverter (See Figure 4). The MC74AC138/74ACT138 can be used as an 8-output demultiplexer by using one of the active LOW Enable inputs as the data input and the other Enable inputs as strobes. The Enable inputs which are not used must be permanently tied to their appropriate active–HIGH or active–LOW state.

TRUTH TABLE

	Inputs					Outputs							
E ₁	E ₂	E ₃	A ₀	A ₁	A ₂	\overline{O}_0	\overline{O}_1	\overline{O}_2	\overline{O}_3	\overline{O}_4	\overline{O}_5	\overline{O}_6	\overline{O}_7
Н	Χ	Χ	Χ	Χ	Χ	Н	Н	Н	Н	Н	Н	Н	Н
Х	Н	Χ	X	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
Χ	Х	L	Χ	Х	Χ	Н	Н	Н	Н	Н	Н	Н	Н
١.	١.						l	١	١	١	١	٠	
L	L	Н	L	L	L	L	Н	Н	Н	Н	Н	Н	Н
L	L	Н	Н	L	L	Н	L	Н	Н	Н	Н	Н	Н
L	L	Н	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н
L	L	Н	Н	Н	L	Н	Н	Н	L	Н	Н	Н	Н
L	L	Н	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н
L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н
L	L	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	L	Н
L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L

H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial



NOTE: This diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Figure 3. Logic Diagram

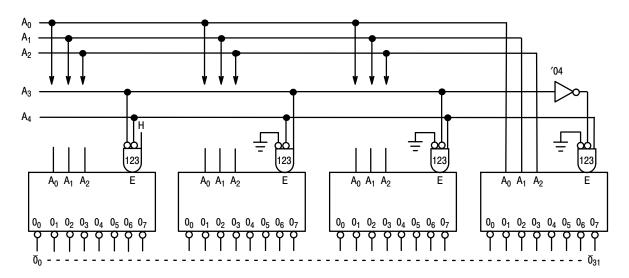


Figure 4. Expansion to 1-of-32 Decoding

MAXIMUM RATINGS

Parameter		Value	Unit
DC Supply Voltage		-0.5 to +6.5	V
DC Input Voltage		$-0.5 \leq V_I \leq V_{CC} + 0.5$	V
DC Output Voltage	(Note 1)	$-0.5 \le V_O \le V_{CC} + 0.5$	V
DC Input Diode Current		±20	mA
DC Output Diode Current		±50	mA
DC Output Sink/Source Current		±50	mA
DC Supply Current per Output Pin		±50	mA
DC Ground Current per Output Pin		±50	mA
Storage Temperature Range	-65 to +150	°C	
Lead temperature, 1 mm from Case for 10 Seconds		260	°C
Junction temperature under Bias		+ 150	°C
Thermal Resistance (Note 2)	SOIC TSSOP	126 159	°C/W
Power Dissipation in Still Air at 25°C (Note 3)	SOIC TSSOP	995 787	mW
Moisture Sensitivity		Level 1	
Flammability Rating Oxygen Inc	dex: 30% - 35%	UL 94 V-0 @ 0.125 in	
		> 2000 > 1000	V
Latch-Up Performance Above V _{CC} and Below GND a	at 85°C (Note 6)	±100	mA
	DC Supply Voltage DC Input Voltage DC Output Voltage DC Input Diode Current DC Output Diode Current DC Output Sink/Source Current DC Supply Current per Output Pin DC Ground Current per Output Pin Storage Temperature Range Lead temperature, 1 mm from Case for 10 Seconds Junction temperature under Bias Thermal Resistance (Note 2) Power Dissipation in Still Air at 25°C (Note 3) Moisture Sensitivity Flammability Rating Oxygen Inc ESD Withstand Voltage Human Body Charged Device	DC Supply Voltage DC Input Voltage DC Output Voltage DC Output Diode Current DC Output Diode Current DC Output Sink/Source Current DC Supply Current per Output Pin DC Ground Current per Output Pin Storage Temperature Range Lead temperature, 1 mm from Case for 10 Seconds Junction temperature under Bias Thermal Resistance (Note 2) Power Dissipation in Still Air at 25°C (Note 3) SOIC TSSOP Moisture Sensitivity Flammability Rating Oxygen Index: 30% – 35% ESD Withstand Voltage Human Body Model (Note 4) Charged Device Model (Note 5)	DC Supply Voltage $-0.5 \text{ to} +6.5$ DC Input Voltage $-0.5 \leq V_{I} \leq V_{CC} + 0.5$ DC Output Voltage $(Note \ 1) -0.5 \leq V_{O} \leq V_{CC} + 0.5$ DC Input Diode Current ± 20 DC Output Diode Current ± 50 DC Output Sink/Source Current ± 50 DC Supply Current per Output Pin ± 50 DC Ground Current per Output Pin ± 50 Storage Temperature Range $-65 \text{ to} +150$ Lead temperature, 1 mm from Case for 10 Seconds 260 Junction temperature under Bias $+150$ Thermal Resistance (Note 2) $SOIC \\ TSSOP \\ 159$ Power Dissipation in Still Air at 25°C (Note 3) $SOIC \\ TSSOP \\ TS$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I_O absolute maximum rating must be observed.

- 2. The package thermal impedance is calculated in accordance with JESD51-7.
- 3. 500 mW at 65°C; derate to 300 mW by 10 mW/ from 65°C to 85°C.
- 4. Tested to EIA/JESD22-A114-A.
- 5. Tested to JESD22-C101-A.
- 6. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Тур	Max	Unit		
.,	O and Mallana	'AC	2.0	5.0	6.0	.,		
V _{CC}	Supply Voltage	'ACT	4.5	5.0	5.5	V		
V _{IN} , V _{OUT}	DC Input Voltage, Output Voltage (Ref. to GND)	0	-	V _{CC}	V			
t _r , t _f		V _{CC} @ 3.0 V	-	150	-			
	Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs	V _{CC} @ 4.5 V	-	40	-	ns/V		
	, to bevious except estimate inputs	V _{CC} @ 5.5 V	-	25	-			
	Input Rise and Fall Time (Note 2)	V _{CC} @ 4.5 V	-	10	-	0 /		
t _r , t _f	'ACT Devices except Schmitt Inputs	V _{CC} @ 5.5 V	-	8.0	-	ns/V		
T _A	Operating Ambient Temperature Range	-40	25	85	°C			
I _{OH}	Output Current - High	-	_	-24	mA			
I _{OL}	Output Current - Low	-	_	24	mA			

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

- V_{IN} from 30% to 70% V_{CC}; see individual Data Sheets for devices that differ from the typical input rise and fall times.
 V_{IN} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

			74	AC	74AC	Unit	
Symbol	Parameter	V _{CC} (V)	T _A =	+25°C	T _A = -40°C to +85°C		Conditions
			Тур	Gua	ranteed Limits		
V _{IH}	Minimum High Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	٧	V _{OUT} = 0.1 V or V _{CC} – 0.1 V
V _{IL}	Maximum Low Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	٧	V _{OUT} = 0.1 V or V _{CC} - 0.1 V
V _{OH}	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	٧	I _{OUT} = -50 μA
		3.0 4.5 5.5	- - -	2.56 3.86 4.86	2.46 3.76 4.76	V	$*V_{IN} = V_{IL} \text{ or } V_{IH}$ -12 mA I_{OH} -24 mA -24 mA
V _{OL}	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	٧	I _{OUT} = 50 μA
		3.0 4.5 5.5	- - -	0.36 0.36 0.36	0.44 0.44 0.44	V	*V _{IN} = V _{IL} or V _{IH} 12 mA I _{OL} 24 mA 24 mA
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	V _I = V _{CC} , GND
I _{OLD}	†Minimum Dynamic	5.5	-	_	75	mA	V _{OLD} = 1.65 V Max
I _{OHD}	Output Current	5.5	-	-	-75	mA	V _{OHD} = 3.85 V Min
I _{CC}	Maximum Quiescent Supply Current	5.5	-	8.0	80	μА	V _{IN} = V _{CC} or GND

^{*}All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC} .

AC CHARACTERISTICS

					74AC		74	AC	Unit
Symbol	Parame		′сс* (V)		λ = +25°(L = 50 p		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ $C_L = 50 \text{ pF}$		
			1	Min	Тур	Max	Min	Max	
t _{PLH}	Propagation Delay A_n to \overline{O}_n		3.3 5.0	1.5 1.5	8.5 6.5	13.0 9.5	1.5 1.5	15.0 10.5	ns
t _{PHL}	Propagation Delay A_n to \overline{O}_n		3.3 5.0	1.5 1.5	8.0 6.0	12.5 9.0	1.5 1.5	14.0 10.5	ns
t _{PLH}	Propagation Delay \overline{E}_1 or \overline{E}_2 to \overline{O}_n		3.3 5.0	1.5 1.5	11.0 8.0	15.0 11.0	1.5 1.5	16.0 12.0	ns
t _{PHL}	Propagation Delay \overline{E}_1 or \overline{E}_2 to \overline{O}_n		3.3 5.0	1.5 1.5	9.5 7.0	13.5 9.5	1.5 1.5	15.0 10.5	ns
t _{PLH}	Propagation Delay E_3 to \overline{O}_n		3.3 5.0	1.5 1.5	11.0 8.0	15.5 11.0	1.5 1.5	16.5 12.5	ns
t _{PHL}	Propagation Delay E_3 to \overline{O}_n		3.3 5.0	1.5 1.5	8.5 6.0	13.0 8.0	1.5 1.0	14.0 9.5	ns

^{*}Voltage Range 3.3 V is 3.3 V ± 0.3 V. *Voltage Range 5.0 V is 5.0 V ± 0.5 V.

DC CHARACTERISTICS

			74	ACT	74ACT		
Symbol	Parameter	V _{CC} (V)	T _A = -	+25°C	T _A = -40°C to +85°C	Unit	Conditions
			Тур	Gua	ranteed Limits		
V _{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V
V _{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	V _{OUT} = 0.1 V or V _{CC} – 0.1 V
V _{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I _{OUT} = -50 μA
		4.5 5.5	- -	3.86 4.86	3.76 4.76	V	*V _{IN} = V _{IL} or V _{IH} -24 mA I _{OH} -24 mA
V _{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I _{OUT} = 50 μA
		4.5 5.5	- -	0.36 0.36	0.44 0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ Q_{IOL} Q_{IOL} Q_{IM} Q_{IM}
I _{IN}	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	V _I = V _{CC} , GND
ΔI_{CCT}	Additional Max. I _{CC} /Input	5.5	0.6	-	1.5	mA	V _I = V _{CC} - 2.1 V
I _{OLD}	†Minimum Dynamic	5.5	-	_	75	mA	V _{OLD} = 1.65 V Max
I _{OHD}	Output Current	5.5	-	-	-75	mA	V _{OHD} = 3.85 V Min
Icc	Maximum Quiescent Supply Current	5.5	-	8.0	80	μΑ	V _{IN} = V _{CC} or GND

^{*}All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS

				74ACT		744	CT	Unit
Symbol	Parameter	V _{CC} * (V)		գ = +25° L = 50 p		$T_A = -40$ °C to +85°C $C_L = 50 \text{ pF}$		
			Min	Тур	Max	Min	Max	
t _{PLH}	Propagation Delay A_n to \overline{O}_n	5.0	1.5	7.0	10.5	1.5	11.5	ns
t _{PHL}	Propagation Delay A_n to \overline{O}_n	5.0	1.5	6.5	10.5	1.5	11.5	ns
t _{PLH}	Propagation Delay \overline{E}_1 or \overline{E}_2 to \overline{O}_n	5.0	2.5	8.0	11.5	2.0	12.5	ns
t _{PHL}	Propagation Delay \overline{E}_1 or \overline{E}_2 to \overline{O}_n	5.0	2.0	7.5	11.5	2.0	12.5	ns
t _{PLH}	Propagation Delay $E_{3 \text{ to }} \overline{O}_n$	5.0	2.5	8.0	12.0	2.0	13.0	ns
t _{PHL}	Propagation Delay E_3 to \overline{O}_n	5.0	2.0	6.5	10.5	1.5	11.5	ns

^{*}Voltage Range 5.0 V is 5.0 V \pm 0.5 V

CAPACITANCE

Symbol	Parameter	Value Typ	Unit	Test Conditions	
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = 5.0 V	
C _{PD}	Power Dissipation Capacitance	60	pF	V _{CC} = 5.0 V	

ORDERING INFORMATION

Device Order Number	Marking	Package	Shipping [†]	
MC74AC138DG	AC138	SOIC-16 (Pb-Free)	48 Units / Rail	
MC74AC138DR2G	AC138	SOIC-16 (Pb-Free)	2500 Tape & Reel	
MC74AC138DTR2G	AC 138	TSSOP-16 (Pb-Free)	2500 Tape & Reel	
MC74ACT138DG	ACT138	SOIC-16 (Pb-Free)	48 Units / Rail	
MC74ACT138DR2G	ACT138	SOIC-16 (Pb-Free)	2500 Tape & Reel	
MC74ACT138DR2G-Q*	ACT138	SOIC-16 (Pb-Free)	2500 Tape & Reel	
MC74ACT138DTR2G	ACT 138	TSSOP-16 (Pb-Free)	2500 Tape & Reel	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP

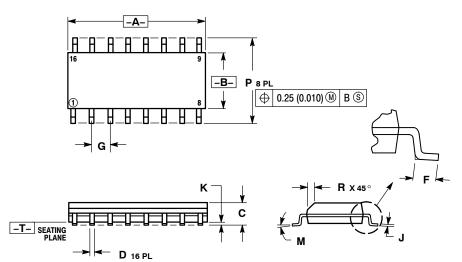
Capable.





SOIC-16 CASE 751B-05 **ISSUE K**

DATE 29 DEC 2006



⊕ 0.25 (0.010) M T B S A S

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD ENGREPHING.
- PROTRUSION.

 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES		
DIM	MIN MAX		MIN	MAX		
Α	9.80	10.00	0.386	0.393		
В	3.80	4.00	0.150	0.157		
C	1.35	1.75	0.054	0.068		
D	0.35	0.49	0.014	0.019		
F	0.40	1.25	0.016	0.049		
G	1.27	BSC	0.050 BSC			
J	0.19	0.25	0.008	0.009		
K	0.10	0.25	0.004	0.009		
M	0°	7°	0°	7°		
Р	5.80	6.20	0.229	0.244		
R	0.25	0.50	0.010	0.019		

STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:		
	COLLECTOR		CATHODE		COLLECTOR, DYE #1		COLLECTOR, DYE #1	1
2.	BASE	2.	ANODE	2.	BASE, #1	2.	COLLECTOR, #1	
3.	EMITTER	3.	NO CONNECTION	3.	EMITTER, #1	3.	COLLECTOR, #2	
4.	NO CONNECTION	4.	CATHODE	4.	COLLECTOR, #1	4.	COLLECTOR, #2	
5.	EMITTER	5.	CATHODE	5.	COLLECTOR, #2	5.	COLLECTOR, #3	
6.	BASE	6.	NO CONNECTION	6.	BASE, #2	6.	COLLECTOR, #3	
7.	COLLECTOR	7.	ANODE	7.	EMITTER, #2	7.	COLLECTOR, #4	
8.	COLLECTOR	8.	CATHODE	8.	COLLECTOR, #2	8.	COLLECTOR, #4	
9.	BASE	9.	CATHODE	9.	COLLECTOR, #3	9.	BASE, #4	
10.	EMITTER	10.	ANODE	10.	BASE, #3	10.	EMITTER, #4	
11.	NO CONNECTION	11.	NO CONNECTION	11.		11.	BASE, #3	
12.	EMITTER	12.	CATHODE	12.	COLLECTOR, #3	12.	EMITTER, #3	DECOMMENDED
13.	BASE	13.	CATHODE	13.	COLLECTOR, #4	13.	BASE, #2	RECOMMENDED
14.	COLLECTOR	14.	NO CONNECTION	14.	BASE, #4	14.		SOLDERING FOOTPRINT*
15.	EMITTER	15.	ANODE	15.	EMITTER, #4	15.	BASE, #1	
16.	COLLECTOR	16.	CATHODE	16.	COLLECTOR, #4	16.	EMITTER, #1	8X
								← 6.40 →
STYLE 5:		STYLE 6:		STYLE 7:				
PIN 1.	DRAIN, DYE #1	PIN 1.	CATHODE	PIN 1.	SOURCE N-CH			16X 1.12 ← ➤
2.	DRAIN, #1	2.	CATHODE	2.	COMMON DRAIN (OUTPUT	Γ)		
3.	DRAIN, #2	3.	CATHODE	3.	COMMON DRAIN (OUTPUT	Γ)	1	1 16
4.	DRAIN, #2	4.	CATHODE	4.	GATE P-CH		<u> </u>	
5.	DRAIN, #3	5.	CATHODE	5.	COMMON DRAIN (OUTPUT		_	
6.	DRAIN, #3	6.	CATHODE	6.	COMMON DRAIN (OUTPUT		16X	·
7.	DRAIN, #4		CATHODE	7.	COMMON DRAIN (OUTPUT	Γ)	0.58 -	
8.	DRAIN, #4	8.	CATHODE	8.	SOURCE P-CH			
9.	GATE, #4	9.	ANODE	9.	SOURCE P-CH	_		
10.	SOURCE, #4	10.	ANODE	10.	COMMON DRAIN (OUTPUT		-	
11.	GATE, #3	11.	ANODE	11.	COMMON DRAIN (OUTPUT			
12.	SOURCE, #3	12.	ANODE	12.	COMMON DRAIN (OUTPUT	1)		
13.	GATE, #2	13.	ANODE	13.	GATE N-CH	- \		
14.	SOURCE, #2		ANODE	14.	COMMON DRAIN (OUTPUT			\ PITCH
15. 16.	GATE, #1 SOURCE, #1	15. 16.	ANODE ANODE	15. 16.	COMMON DRAIN (OUTPUT SOURCE N-CH	1)		
10.	500RCE, #1	10.	ANODE	10.	SOURCE N-CH			
								□8 9 -
								* *
								'
								DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	SOIC-16		PAGE 1 OF 1	

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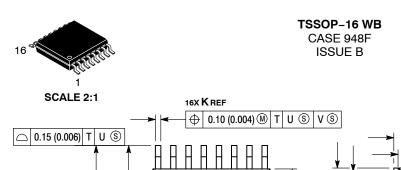
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☐ 0.15 (0.006)

PIN 1 IDENT.

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DATE 19 OCT 2006

NOTES

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SECTION N-N

0.25 (0.010)

J1

В

-U-

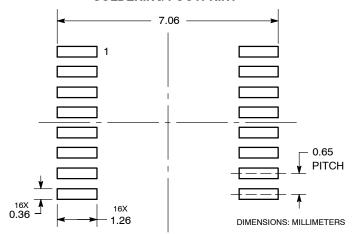
- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT
- EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE
 INTERLEAD FLASH OR PROTRUSION.
- INTERLEAD FLASH OR PROTRUSION.
 INTERLEAD FLASH OR PROTRUSION SHALL
 NOT EXCEED 0.25 (0.010) PER SIDE.
 DIMENSION K DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABILE DAMBAR
 PROTRUSION SHALL BE 0.08 (0.003) TOTAL
 IN EXCESS OF THE K DIMENSION AT
 MAXIMUM MATERIAL CONDITION.
 TERMINIAL NILMBERS ADE SUCIUMI ECIP.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
Н	0.18	0.28	0.007	0.011
7	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
М	00	00	00	0 0

DETAIL E -W-☐ 0.10 (0.004) **DETAIL E** SEATING PLANE D

RECOMMENDED SOLDERING FOOTPRINT*

-V-



^{*}For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



= Specific Device Code XXXX Α = Assembly Location

= Wafer Lot L = Year W = Work Week G or • = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.

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